

Data sheet acquired from Harris Semiconductor SCHS073C – Revised October 2003

## CMOS 8-Channel Data Selector

High-Voltage Types (20-Volt Rating)

■ CD4512B is an 8-channel data selector featuring a three-state output that can interface directly with, and drive, data lines of bus-oriented systems.

The CD4512B-series types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, MT, and NSR suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

# CD4512B Types

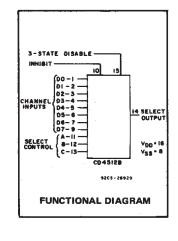
#### Features:

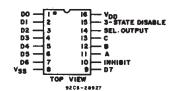
- **3**-state output
- Standardized, symmetrical output characteristics
- 100% tested for quiescent current at 20 V
- 5-V, 10-V, and 15-V parametric ratings
- Maximum input current of 1 μA at 18 V over full packagetemperature range; 100 nA at 18 V and 25°C
- Noise margin (over full package-temperature range):

 Meets all requirements of JEDEC Tentative Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

#### Applications:

- Digital multiplexing
- Number-sequence generation
- Signal gating



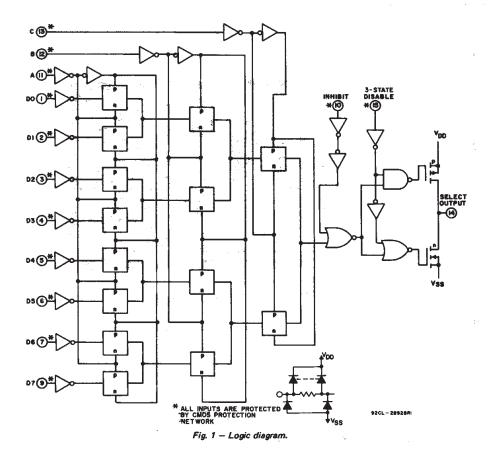


**TERMINAL ASSIGNMENT** 

#### RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

|   | LIN  | IITS | AMUTO |
|---|------|------|-------|
| CHARACTERISTIC  | MIN. | MAX. | UNITS |
| Supply-Voltage Range (For T <sub>A</sub> = Full Package<br>Temperature Range) | 3    | 18   | · V   |



**TRUTH TABLE** 

|     |     | 1   |        | 1770-   |            |
|-----|-----|-----|--------|---------|------------|
| SEL | COM | NT. | INH    | 3-STATE | SEL        |
| Α   | В   | С   | 114171 | DISABLE | OUTPUT     |
| 0   | 0   | 0   | 0      | 0       | D0         |
| 1   | 0   | 0   | 0      | 0       | D1         |
| 0   | 1   | 0   | 0      | 0       | D2         |
| 1   | 1   | 0   | 0      | 0       | D3         |
| 0   | 0   | 1   | 0      | 0       | D4         |
| 1   | 0   | 1   | 0      | 0       | <b>D</b> 5 |
| 0   | 1   | 1   | 0      | 0       | D6         |
| 1   | 1   | 1   | 0      | 0       | D7         |
| х   | x   | X   | 1      | 0       | 0          |
| х   | х   | Ιx  | х      | 1       | High Z     |

1 = High Level

0 = Low Level

X = Don't Care

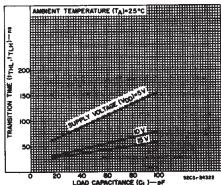


Fig. 2 — Typical transition time as a function of load capacitance.

## CD4512B Types

| MAXIMUM RATINGS, Absolute-Maximum Values:                                 |  |
|---|--|
| DC SUPPLY-VOLTAGE RANGE, (VDD)  |  |
| Voltages referenced to V <sub>SS</sub> Terminal)                          |  |
| INPUT VOLTAGE RANGE, ALL INPUTS0.5V to V <sub>DD</sub> +0.5V              |  |
| DC INPUT CURRENT, ANY ONE INPUT   |  |
| POWER DISSIPATION PER PACKAGE (PD):                                       |  |
| For T <sub>A</sub> = -55°C to +100°C                                      |  |
| For T <sub>A</sub> = +100°C to +125°C                                     |  |
| DEVICE DISSIPATION PER OUTPUT TRANSISTOR                                  |  |
| FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Types)               |  |
| OPERATING-TEMPERATURE RANGE (T <sub>A</sub> )55°C to +125°C               |  |
| STORAGE TEMPERATURE RANGE (T <sub>stg</sub> )65°C to +150°C               |  |
| LEAD TEMPERATURE (DURING SOLDERING):                                      |  |
| At distance 1/16 ± 1/32 inch (1.59 ± 0.79mm) from case for 10s max +265°C |  |

| 5 to | LOW (SIMK) CURRENT (I <sub>OL</sub> ) mA | A | WEN | EN | G. |  | (T   1   1   1   1   1   1   1   1   1 |  | 0 1100 1100 | TA | GE | 3 |  |  |  |  |
|---|--|---|-----|----|----|--|--|--|-------------|----|----|---|--|--|--|--|
|   | 5 0                                      |   | Ź   |    | í  |  | V2                                     |  |             |    |    |   |  |  |  |  |

Fig. 3 — Typical output low (sink) current characteristics.

| CHARAC-<br>TERISTIC                      |                       | DITIO                  | r :                    |         | LIMITS AT INDICATED TEMPERATURES (°C) |           |       |       |                   |            |           |  |  |
|--|-----------------------|------------------------|------------------------|---------|---------------------------------------|-----------|-------|-------|-------------------|------------|-----------|--|--|
|  | V <sub>O</sub><br>(V) | V <sub>IN</sub><br>(V) | V <sub>DD</sub><br>(V) | 55      | <b>–40</b>                            | +85       | +125  | Min.  | Typ.              | Max.       | S         |  |  |
| Quiescent                                | _                     | 0,5                    | 5                      | 5       | 5                                     | 150       | 150   | -     | 0.04              | 5          |           |  |  |
| Device                                   |                       | 0,10                   | 10                     | 10      | 10                                    | 300       | 300   | -     | 0.04              | 10         | μΑ        |  |  |
| Current,                                 | -                     | 0,15                   | 15                     | 20      | 20                                    | 600       | 600   | _     | 0.04              | 20         | ļ         |  |  |
| - DD Max.                                | _                     | 0,20                   | 20                     | 100     | 100                                   | 3000      | 3000  |       | 0.08              | 100        | İ         |  |  |
| Output Low                               | 0.4                   | 0,5                    | 5                      | 0.64    | 0.61                                  | 0.42      | 0.36  | 0.51  | 1                 | -          |           |  |  |
| (Sink) Current                           | 0.5                   | 0,10                   | 10                     | 1.6     | 1.5                                   | 1.1       | 0.9   | 1.3   | 2.6               | _          |           |  |  |
| OL Min.                                  | 1.5                   | 0,15                   | 15                     | 4.2     | 4                                     | 2.8       | 2.4   | 3.4   | 6.8               | _          |           |  |  |
| Output High                              | 4.6                   | 0,5                    | 5                      | -0.64   | 0.61                                  | -0.42     | -0.36 | -0.51 | -1                | _          | m         |  |  |
| (Source)                                 | 2.5                   | 0,5                    | 5                      | -2      | -1.8                                  | -1.3      | -1.15 | -1.6  | -3.2              | _          |           |  |  |
| Current,<br>IOH Min.                     | 9.5                   | 0,10                   | 10                     | 1.6     | -1.5                                  | -1.1      | -0.9  | -1.3  | -2.6              | -          |           |  |  |
| 10H WIIII                                | 13.5                  | 0,15                   | 15                     | -4.2    | -4                                    | -2.8      | -2.4  | -3.4  | -6.8              | _          |           |  |  |
| Output Voltage:                          | _                     | 0,5                    | 5                      |         | 0.                                    | .05       | •     | _     | 0                 | 0.05       |           |  |  |
| Low-Level,                               | _                     | 0,10                   | 10                     |         | 0.                                    | .05       |       | _     | 0                 | 0.05       |           |  |  |
| VOL Max.                                 | _                     | 0,15                   | 15                     |         | 0.                                    | .05       |       | _     | 0                 | 0.05       | V         |  |  |
| Output                                   | _                     | 0,5                    | 5                      |         | 4.                                    | .95       |       | 4.95  | 5                 | - <u>-</u> |           |  |  |
| Voltage:<br>High-Level,                  | _                     | 0,10                   | 10                     |         | 9                                     | 95        |       | 9.95  | 10                | 1          |           |  |  |
| VOH Min.                                 | _                     | 0,15                   | 15                     | W. L. C | 14                                    | 95        |       | 14.95 | 15                | - F        |           |  |  |
| Input Low                                | 0.5,4.5               |                        | 5                      |         | 4                                     | 1.5       |       | -     |                   | 1.5        |           |  |  |
| Voltage                                  | 1,9                   | _                      | 10                     |         |                                       | 3         |       |       |                   | 3          |           |  |  |
| V <sub>IL</sub> Max.                     | 1.5,13.5              | _                      | 15                     |         |                                       | 4         |       | 1     | -                 | 4          | v         |  |  |
| Input High                               | 0.5,4.5               | _                      | 5                      |         |                                       | 3.5       |       | 3.5   | _                 | 1          | <b>7.</b> |  |  |
| Voltage,                                 | 1,9                   |                        | 10                     |         | 162                                   | 7         |       | 7     |                   | -          |           |  |  |
| V <sub>IH</sub> Min.                     | 1.5,13.5              |                        | 15                     |         |                                       | 11        |       | 11    | -                 | * <b>-</b> |           |  |  |
| Input Current<br>IN Max.                 | -                     | 0,18                   | 18                     | ±0.1    | ±0.1                                  | <b>‡1</b> | ±1    |       | ±10 <sup>-5</sup> | ±0.1       | μ         |  |  |
| 3-State Output Leakage Current IOUT Max. | 0,18                  | 0,18                   | 18                     | ±0.4    | ±0.4                                  | ±12       | ±12   |       | ±10 <sup>-4</sup> | ±0.4       | μ         |  |  |

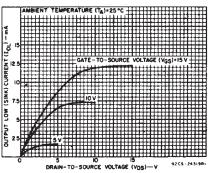


Fig. 4 — Minimum output low (sink) current characteristics.

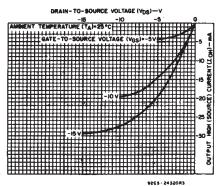


Fig. 5 — Typical output high (source) current characteristics.

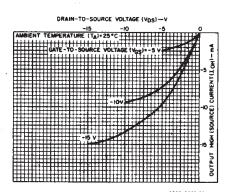


Fig. 6 — Minimum output high (source) current characteristics.

# DYNAMIC ELECTRICAL CHARACTERISTICS at T\_A = 25°C, Input $t_r,t_f$ = 20 ns, C\_L = 50 pF, R\_L = 200 $k\Omega$

| CHARACTERISTIC   | TEST CONDITIONS        | LIN             | MITS              | UNITS |
|--|------------------------|-----------------|-------------------|-------|
| The second secon | V <sub>DD</sub><br>(V) | Тур.            | Max.              |       |
| Propagation Delay Time, tpHL, tpLH Inhibit to Output   | 5<br>10<br>15          | 140<br>70<br>50 | 280<br>140<br>100 |       |
| "A" Select to Output   | 5<br>10<br>15          | 200<br>85<br>60 | 400<br>170<br>120 | ns    |
| Data to Output   | 5<br>10<br>15          | 180<br>75<br>55 | 360<br>150<br>110 |       |
| 3-State Disable Delay Time: <sup>†</sup> PZL, <sup>†</sup> PLZ, <sup>†</sup> PHZ, <sup>†</sup> PZH   | 5<br>10<br>15          | 60<br>30<br>20  | 120<br>60<br>40   | ns    |
| Transition Time, t <sub>THL</sub> , t <sub>TLH</sub>   | 5<br>10<br>15          | 100<br>50<br>40 | 200<br>100<br>80  | ns    |
| Input Capacitance, C <sub>IN</sub> (Any Input)   |                        | 5               | 7.5               | pF    |

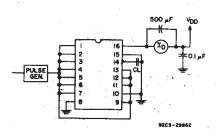


Fig. 9 - Dynamic power dissipation test circuit.

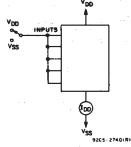


Fig. 10 - Quiescent device current test circuit.

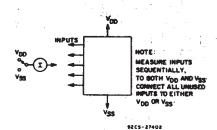


Fig. 11 - Input current test circuit.

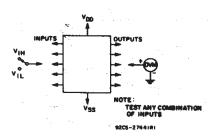
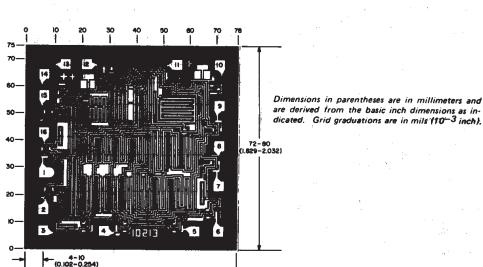


Fig. 12 - Input voltage test circuit.



Dimensions and pad layout for CD4512BH

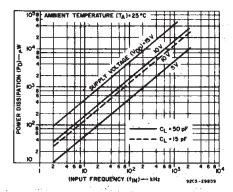


Fig. 7 — Typical dyanamic power dissipation as a function of frequency.

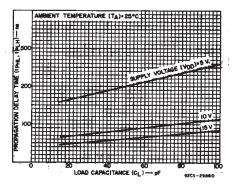


Fig. 8 — Typical propagation delay time as a function of load capacitance ("A" select to output).

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#### PACKAGING INFORMATION

| Orderable Device | Status (1) | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan            | Lead finish/<br>Ball material | MSL Peak Temp      | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|------------------|------------|--------------|--------------------|------|----------------|---------------------|-------------------------------|--------------------|--------------|-------------------------|---------|
| CD4512BE         | ACTIVE     | PDIP         | N                  | 16   | 25             | RoHS & Green        | NIPDAU                        | N / A for Pkg Type | -55 to 125   | CD4512BE                | Samples |
| CD4512BEE4       | ACTIVE     | PDIP         | N                  | 16   | 25             | RoHS & Green        | NIPDAU                        | N / A for Pkg Type | -55 to 125   | CD4512BE                | Samples |
| CD4512BF         | ACTIVE     | CDIP         | J                  | 16   | 25             | Non-RoHS<br>& Green | SNPB                          | N / A for Pkg Type | -55 to 125   | CD4512BF                | Samples |
| CD4512BF3A       | ACTIVE     | CDIP         | J                  | 16   | 1              | Non-RoHS<br>& Green | SNPB                          | N / A for Pkg Type | -55 to 125   | CD4512BF3A              | Samples |
| CD4512BM96       | ACTIVE     | SOIC         | D                  | 16   | 2500           | RoHS & Green        | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | CD4512BM                | Samples |
| CD4512BM96G4     | ACTIVE     | SOIC         | D                  | 16   | 2500           | RoHS & Green        | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | CD4512BM                | Samples |
| CD4512BNSR       | ACTIVE     | SO           | NS                 | 16   | 2000           | RoHS & Green        | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | CD4512B                 | Samples |
| CD4512BPW        | ACTIVE     | TSSOP        | PW                 | 16   | 90             | RoHS & Green        | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | CM512B                  | Samples |
| CD4512BPWR       | ACTIVE     | TSSOP        | PW                 | 16   | 2000           | RoHS & Green        | NIPDAU                        | Level-1-260C-UNLIM | -55 to 125   | CM512B                  | Samples |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

## **PACKAGE OPTION ADDENDUM**

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(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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#### OTHER QUALIFIED VERSIONS OF CD4512B, CD4512B-MIL:

Catalog: CD4512B

Military: CD4512B-MIL

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

## **PACKAGE MATERIALS INFORMATION**

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## TAPE AND REEL INFORMATION



# TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

| A0 | Dimension designed to accommodate the component width     |
|----|---|
| В0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device     | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| CD4512BM96 | SOIC            | D                  | 16 | 2500 | 330.0                    | 16.4                     | 6.5        | 10.3       | 2.1        | 8.0        | 16.0      | Q1               |
| CD4512BNSR | so              | NS                 | 16 | 2000 | 330.0                    | 16.4                     | 8.2        | 10.5       | 2.5        | 12.0       | 16.0      | Q1               |
| CD4512BPWR | TSSOP           | PW                 | 16 | 2000 | 330.0                    | 12.4                     | 6.9        | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |



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#### \*All dimensions are nominal

| Device     | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|------------|--------------|-----------------|------|------|-------------|------------|-------------|
| CD4512BM96 | SOIC         | D               | 16   | 2500 | 340.5       | 336.1      | 32.0        |
| CD4512BNSR | SO           | NS              | 16   | 2000 | 356.0       | 356.0      | 35.0        |
| CD4512BPWR | TSSOP        | PW              | 16   | 2000 | 356.0       | 356.0      | 35.0        |

## **PACKAGE MATERIALS INFORMATION**

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## **TUBE**



\*All dimensions are nominal

| Device     | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| CD4512BE   | N            | PDIP         | 16   | 25  | 506    | 13.97  | 11230  | 4.32   |
| CD4512BE   | N            | PDIP         | 16   | 25  | 506    | 13.97  | 11230  | 4.32   |
| CD4512BEE4 | N            | PDIP         | 16   | 25  | 506    | 13.97  | 11230  | 4.32   |
| CD4512BEE4 | N            | PDIP         | 16   | 25  | 506    | 13.97  | 11230  | 4.32   |
| CD4512BPW  | PW           | TSSOP        | 16   | 90  | 530    | 10.2   | 3600   | 3.5    |

## D (R-PDS0-G16)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



## D (R-PDSO-G16)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE PACKAGE



- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## **MECHANICAL DATA**

## NS (R-PDSO-G\*\*)

## 14-PINS SHOWN

## PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



## 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

## N (R-PDIP-T\*\*)

## PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOP



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing
- per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.



SOF



## NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOF



#### NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



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